

Agilent HSMF-C113 / C115 Right Angle Tricolor Surface Mount ChipLEDs Data Sheet

Description

The HSMF-C113 / C115 tricolor chip-type LED is designed in an ultra small package for miniaturization. It is the first of its kind to achieve such small packaging for 3 dies. With the freedom to have any combination of colors from mixing of the 3 primary colors, this will yield a wide variety of colors to suit every application and product theme.

The small size, narrow footprint, and low profile make this LED excellent for backlighting, status indication, and front panel illumination applications.

In order to facilitate pick and place operation, this ChipLED is shipped in tape and reel, with 3000 units per reel. The package is compatible with reflow soldering and binned by both color and intensity.

Features

- Common anode
- Small 2.5 x 1.0 x 1.0 mm package
- Diffused optics
- Available in 8 mm tape on 7" diameter reels
- High brightness using AlInGaP and InGaN die technology
- Compatible with reflow soldering

Applications

- Backlighting
- Status indicator
- Front panel indicator
- Office automation, home appliances, industrial equipment

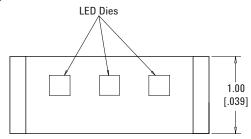
Device Selection Guide

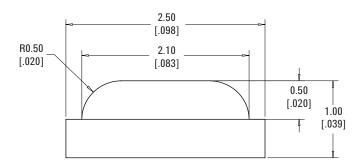
Part Number	Color	Package Description
HSMF-C113	AllnGaP Red / AllnGaP Green / InGaN Blue	Untinted, Diffused
HSMF-C115	AllnGaP Red / InGaN Green / InGaN Blue	Untinted, Diffused

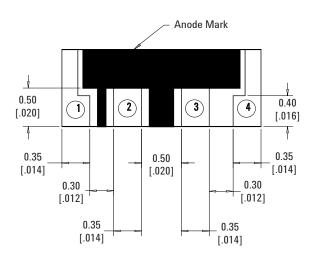
CAUTION: HSMF-C113 and HSMF-C115 LEDs are Class 1 ESD sensitive. Please observe appropriate precautions during handling and processing. Refer to Agilent Technologies Application Note AN-1142 for additional details.



Package Dimensions







POLARITY		HSMF-C113	HSMF-C115
		InGaN BLUE	InGaN BLUE
2 -	3	AllnGaP RED	AllnGaP RED
	4	AlinGaP GREEN	InGaN GREEN

Notes:

- 1. All Dimensions in millimeteres (inches)
- 2. Tolerance is $\pm 0.1 mm$ (± 0.004 in) unless otherwise specified

Absolute Maximum Ratings at $T_A = 25^{\circ}\text{C}$

Parameter	AlinGaP Red	AlinGaP Green	InGaN Green	InGaN Blue	Units
DC Forward Current ^[1,3]	20	20	20	20	mA
Power Dissipation ^[1]	48	52	78	78	mW
DC Forward Current ^[2]	15	15	15	15	mA
Power Dissipation ^{[2}]	36	39	59	59	mW
Reverse Voltage ($I_R = 100\mu A$)	5	5	5	5	V
LED Junction Temperature	95	95	95	95	°C
Operating Temperature Range	-30 to +85				°C
Storage Temperature Range	-40 to +85				°C
Soldering Temperature	See IR soldering profile (Figure 6 & 7)				

Notes:

- 1. Applies when single LED is lit up.
- 2. Applies when all 3 LEDs are lit up simultaneously.
- 3. Derate linearly as shown in Figure 4.
- 4. Drive currents above 5 mA are recommended for best long term performance.

Electrical Characteristics at $T_A = 25^{\circ}C$

	Forward Voltage VF (Volts) ^[1] @ IF = 20mA		VF (Volts) ^[1] V _R (Volts)		Reverse Breakdown V_R (Volts) @ $I_R = 100 \mu A$	Capacitance C(pF), @ V _F = 0, f = 1MHz	Thermal Resistance Rθ _{J-PIN} (°C/W)
Part Number	Тур.	Max.	Min.	Тур.	Тур.		
AllnGaP Red	1.9	2.4	5	12	550		
AllnGaP Green	2.0	2.6	5	15	300		
InGaN Green	3.4	3.9	5	65	400		
InGaN Blue	3.4	3.9	5	65	400		

Notes:

1.Vf tolerance: ±0.1V

Optical Characteristics at $T_A = 25^{\circ}C$

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		us Intensity mcd) A	Peak Wavelength $\lambda_{\mbox{\tiny peak}}$ (nm)	Color, Dominant Wavelength $\lambda d^{[2]}$ (nm)	Viewing Angle $2\theta_{1/2}^{[3]}$ (Degrees)	Luminous Efficacy ην (lm/W)
Part Number	Min.	Тур.	Typical	Typical	Typical	Typical
AllnGaP Red	28.5	80.0	637	626	120	155
AllnGaP Green	18.0	50.0	570	572	125	570
InGaN Green	71.5	170.0	523	525	125	443
InGaN Blue	28.5	60.0	468	470	125	89

Notes:

- 1. The luminous intensity I_V is measured at the peak of the spatial radiation pattern which may not be aligned with the mechanical axis of the LED package.
- $2. \ \ The \ dominant \ wavelength, \ I_d. \ is \ derived from \ the \ CIE \ Chromaticity \ Diagram \ and \ represents the \ perceived \ color \ of \ the \ device.$
- 3. $\theta_{1/2}$ is the off-axis angle where the luminous intensity is ½ the peak intensity.

CAUTION:

- The above optical performance specifications are valid in the case when single LED is lit up.
- The above product specifications DO NOT provide any guarantee on color mixing, color consistency over time, or uniformity in luminous intensity when more than 1 LED is lit.
- Please refer to Agilent Technologies'
 Application Brief AB D-007 for additional details / explanation on driving the part in parallel circuit.

Light Intensity (I_V) Bin Limits^[1]

	, , , ,		
	Intensity (mcd)		
Bin ID	Minimum	Maximum	
Α	0.11	0.18	
В	0.18	0.29	
С	0.29	0.45	
D	0.45	0.72	
E	0.72	1.10	
F	1.10	1.80	
G	1.80	2.80	
Н	2.80	4.50	
J	4.50	7.20	
K	7.20	11.20	
L	11.20	18.00	
M	18.00	28.50	
N	28.50	45.00	
Р	45.00	71.50	
Q	71.50	112.50	
R	112.50	180.00	
S	180.00	285.00	
T	285.00	450.00	

Tolerance: ±15%

Notes:

 Bin categories are established for classification of products. Products may not be available in all categories. Please contact your Agilent representative for information on current available bins.

AlInGaP Red Color Bin Limits^[1]

	Dom. Wavelength (nm)			
Bin ID	Minimum	Maximum		
	615.0	630.0		
Toleranc	ance : ±1nm			

AlInGaP Green Color Bin Limits^[1]

	Dom. Wavelength (nm)		
Bin ID	Minimum	Maximum	
А	561.5	564.5	
В	564.5	567.5	
С	567.5	570.5	
D	570.5	573.5	
E	573.5	576.5	
Tolerance : ±0.5nm			

InGaN Green Color Bin Limits^[1]

	Dom. Wavelength (nm)		
Bin ID	Minimum	Maximum	
Α	515.0	520.0	
В	520.0	525.0	
С	525.0	530.0	
D	530.0	535.0	
Tolerance : ±1nm			

InGaN Blue Color Bin Limits[1]

	Dom. Wavelength (nm)			
Bin ID	Minimum	Maximum		
Α	460.0	465.0		
В	465.0	470.0		
С	470.0	475.0		
D	475.0	480.0		

 $Tolerance: \pm 1 nm$

Notes:

 Bin categories are established for classification of products. Products may not be available in all categories. Please contact your Agilent representative for information on current available bins.

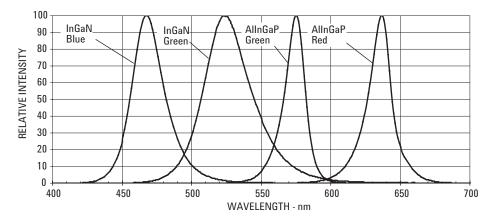


Figure 1. Relative intensity vs. wavelength.

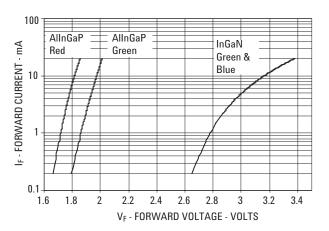


Figure 2. Forward current vs. forward voltage.

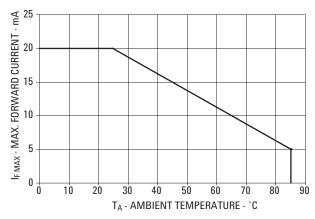


Figure 4. Maximum forward current vs. ambient temperature.

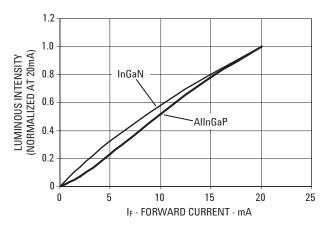


Figure 3. Luminous intensity vs. forward current.

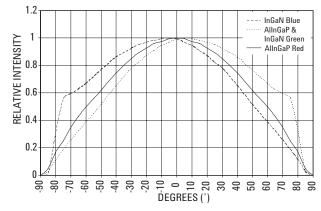


Figure 5. Relative intensity vs. angle.

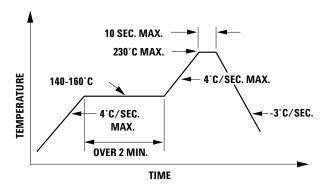


Figure 6. Recommended reflow soldering profile.

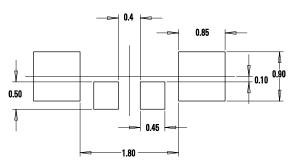


Figure 8. Recommended soldering land pattern.

Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ± 0.1 mm (± 0.004 in.) unless otherwise specified.

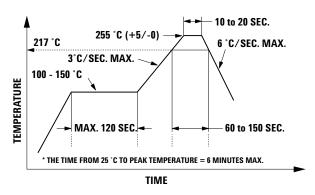
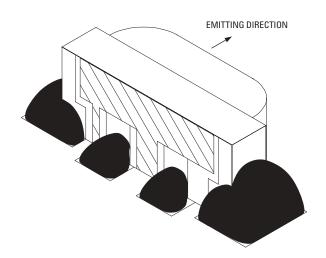


Figure 7. Recommended Pb-free reflow soldering profile.



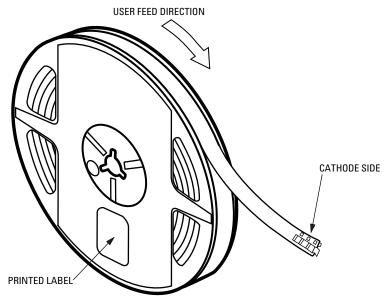


Figure 9. Reeling orientation.

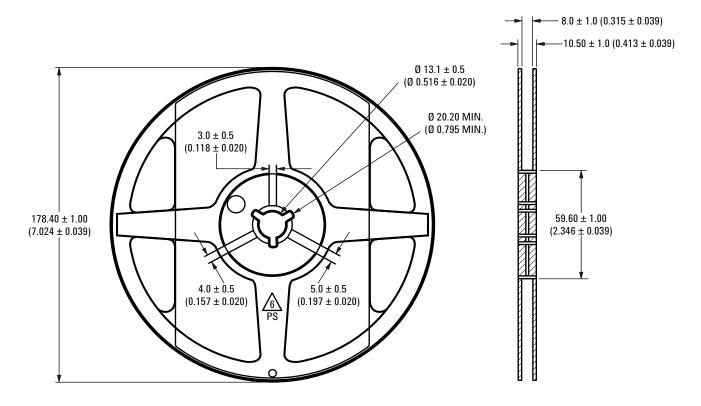
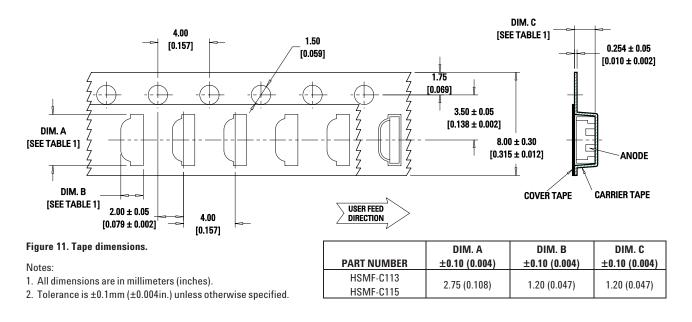


Figure 10. Reel dimensions.



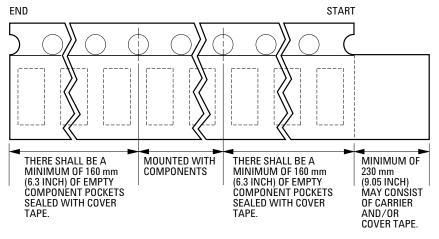


Figure 12. Tape leader and trailer dimensions.

Reflow Soldering:

For more information on reflow soldering, refer to Application Note AN-1060, Surface Mounting SMT LED Indicator Components.

Storage Condition:

5 to 30°C @ 60%RH max.

Baking is required before mounting, if:

- 1. Humidity Indicator Card is > 10% when read at 23 \pm 5°C.
- 2. Device expose to factory conditions <30°C/60%RH more than 672 hours.

Recommended baking condition:

60±5°C for 20 hours.

www.agilent.com/ semiconductors

For product information and a complete list of distributors, please go to our web site.

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